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FOREIGN PATENT DOCUMENTS							
Ref. Desig.	Examiner's Initials	Document Number	Date	Country		Class/ Subclass	Translation Yes No
1.	/GE/	JP 03216287 A	09/24/1991	Japan			Abstract

OTHE	OTHER DOCUMENTS (including Author, Title, Date, Pertinent Pages, etc.)					
Ref Desig.	Examiner's Initials					
1.	/GE/	Mannion et al., "Ablation Thresholds in Ultrafast Laser Micro-Machining of Common Metals in Air, Proceedings of SPIE, Vol. 4876 (2003), pages 470-478.				
2.	/GE/	S. Amoruso et al., "Characterization of Laser-Ablation Plasmas", J. Phys. B: At. Mol. Opt. Phys. 32 (1999) R131-R172, section 2.1.1.				
3.	/GE/	Kautek et al., Laser Ablation of Dielectrics with Pulse Durations Between 20 fs and 3 ps, Appl. Phys. Lett. 69(21), November 18, 1996, pages 3146-3148.				
4.	/GE/	J. Bonse et al., Ultrashort-Pulse Laser Ablation of Indium Phosphide in Air, Appl. Phys. A Volume 72, Issue 1, pages 89-94 (2001).				
5.	/GE/	S. Preuss et al., Time Resolved Dynamics of Subpicosecond Laser Ablation, Appl. Phys. Lett, Vol. 62, No. 23, June 7, 1993.				
6.	/GE/	Schwab et al., Femtosecond-Excimer-Laser Patterning of YBa ₂ Cu ₃ O ₇ Films, Appl. Phys. A, Volume 53, (1991), pages 282-283.				
7.	/GE/	Chen et al., Generation of Submicron Surface Gratings on LiNbO₃ by Ultrashort UV Laser Pulses, Appl. Phys. A, Volume 65, Pages 517-518 (1997).				

Examiner: /Geoffrey S. Evans/ Date Considered: 03/29/2007